Spyridon Pavlidis

List of Publications by Year in descending order

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| # | Article | IF | CITATIONS |
|----|--|-----|-----------|
| 1 | GaN lateral polar junction arrays with 3D control of doping by supersaturation modulated growth: A path toward III-nitride superjunctions. Journal of Applied Physics, 2022, 131, 015703. | 2.5 | 8 |
| 2 | Largeâ€Area, Solarâ€Blind, Subâ€250 nm Detection AlGaN Avalanche Photodiodes Grown on AlN Substrates. Physica Status Solidi - Rapid Research Letters, 2022, 16, . | 2.4 | 9 |
| 3 | Record >10 MV/cm mesa breakdown fields in Al0.85Ga0.15N/Al0.6Ga0.4N high electron mobility transistors on native AlN substrates. Applied Physics Letters, 2022, 120, . | 3.3 | 9 |
| 4 | Schottky contacts to N-polar GaN with SiN interlayer for elevated temperature operation. Applied Physics Letters, 2022, 120, . | 3.3 | 0 |
| 5 | (Invited, Digital Presentation) Exploring Interfaces and Polarity to Realize Vertical III-Nitride Superjunction Devices. ECS Meeting Abstracts, 2022, MA2022-01, 1313-1313. | 0.0 | 0 |
| 6 | On the characteristics of N-polar GaN Schottky barrier contacts with LPCVD SiN interlayers. Applied Physics Letters, 2021, 118, . | 3.3 | 3 |
| 7 | High <i>n</i> -type conductivity and carrier concentration in Si-implanted homoepitaxial AlN. Applied Physics Letters, 2021, 118, . | 3.3 | 25 |
| 8 | On the Ge shallow-to-deep level transition in Al-rich AlGaN. Journal of Applied Physics, 2021, 130, . | 2.5 | 5 |
| 9 | Study on avalanche breakdown and Poole–Frenkel emission in Al-rich AlGaN grown on single crystal AlN. Applied Physics Letters, 2021, 119, . | 3.3 | 10 |
| 10 | Chemical treatment effects on Schottky contacts to metalorganic chemical vapor deposited n-type N-polar GaN. Journal of Applied Physics, 2020, 128, 064501. | 2.5 | 9 |
| 11 | High gain, large area, and solar blind avalanche photodiodes based on Al-rich AlGaN grown on AlN substrates. Applied Physics Letters, 2020, 116, . | 3.3 | 33 |
| 12 | Role of polarity in SiN on Al/GaN and the pathway to stable contacts. Semiconductor Science and Technology, 2020, 35, 055007. | 2.0 | 7 |
| 13 | (Invited) A Path Toward Vertical GaN Superjunction Devices. ECS Transactions, 2020, 98, 69-79. | 0.5 | 6 |
| 14 | p-n-p-Based RF Switches for the Mitigation of Single-Event Transients in a Complementary SiGe BiCMOS Platform. IEEE Transactions on Nuclear Science, 2018, 65, 391-398. | 2.0 | 6 |
| 15 | An Electrostatic Discharge Protection Circuit Technique for the Mitigation of Single-Event Transients in SiGe BiCMOS Technology. IEEE Transactions on Nuclear Science, 2018, 65, 426-431. | 2.0 | 4 |
| 16 | Characterization of AlGaN/GaN HEMTs Using Gate Resistance Thermometry. IEEE Transactions on Electron Devices, 2017, 64, 78-83. | 3.0 | 39 |
| 17 | Fabrication and characterization of CPW transmission lines with CoFe <inf>2</inf> O <inf>4</inf> nanomagnetic thin films. , 2017, , . | | 1 |
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18 3-D printed substrates for MMIC packaging. , 2017, , .

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|----|--|------|-----------|
| 19 | Encapsulated Organic Package Technology for Wideband Integration of Heterogeneous MMICs. IEEE Transactions on Microwave Theory and Techniques, 2017, 65, 438-448. | 4.6 | 11 |
| 20 | Direct correlation between potentiometric and impedance biosensing of antibody-antigen interactions using an integrated system. Applied Physics Letters, 2017, 111, . | 3.3 | 14 |
| 21 | Sizeâ€Scalable and Highâ€Density Liquidâ€Metalâ€Based Soft Electronic Passive Components and Circuits Using Soft Lithography. Advanced Functional Materials, 2017, 27, 1604466. | 14.9 | 107 |
| 22 | Room temperature CO <inf>2</inf> detection using interdigitated capacitors with heteropolysiloxane sensing films. , 2016, , . | | 0 |
| 23 | A 5.4W X-band gallium nitride (GaN) power amplifier in an encapsulated organic package. , 2015, , . | | 10 |
| 24 | Aerosol jet printing for 3-D multilayer passive microwave circuitry. , 2014, , . | | 25 |
| 25 | A feasibility study of flip-chip packaged gallium nitride HEMTs on organic substrates for wideband RF amplifier applications. , 2014, , . | | 8 |
| 26 | A low-cost, encapsulated flip-chip package on organic substrate for wideband gallium nitride (GaN) hybrid amplifiers. , 2014, , . | | 8 |
| 27 | A hybrid GaN/organic X-band transmitter module. , 2013, , . | | 0 |
| 28 | A hybrid GaN/organic X-band transmitter module. , 2013, , . | | 2 |
| 29 | Integrated microfluidic cooling for GaN devices on multilayer organic LCP substrate. , 2013, , . | | 8 |